

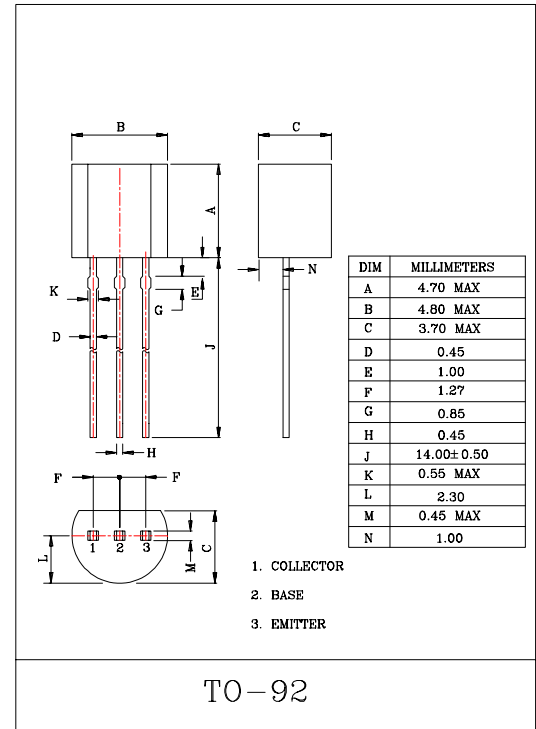
GENERAL PURPOSE APPLICATION.
SWITCHING APPLICATION.

FEATURES

- High Current : $I_C=800\text{mA}$.
- DC Current Gain : $h_{FE}=100\sim 400$ ($V_{CE}=1\text{V}$, $I_C=100\text{mA}$).
- For Complementary with PNP type BC327.

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	45	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	800	mA
Emitter Current	I_E	-800	mA
Collector Power Dissipation	P_C	625	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55~150	$^\circ\text{C}$

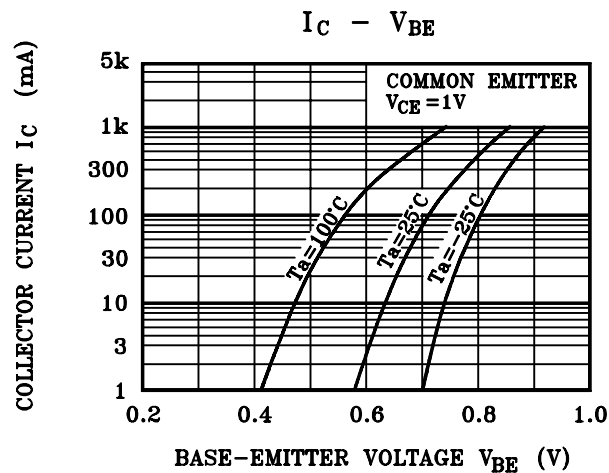
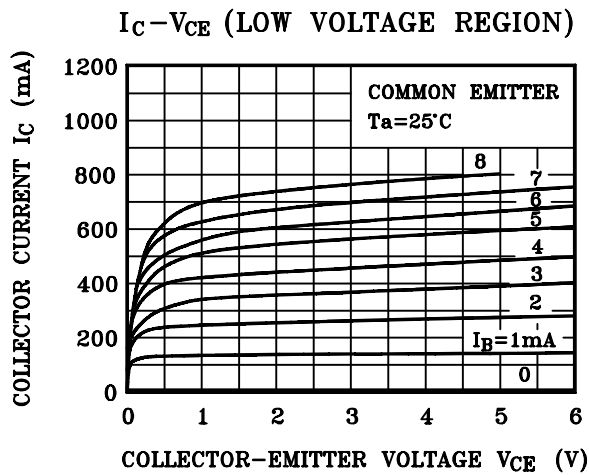
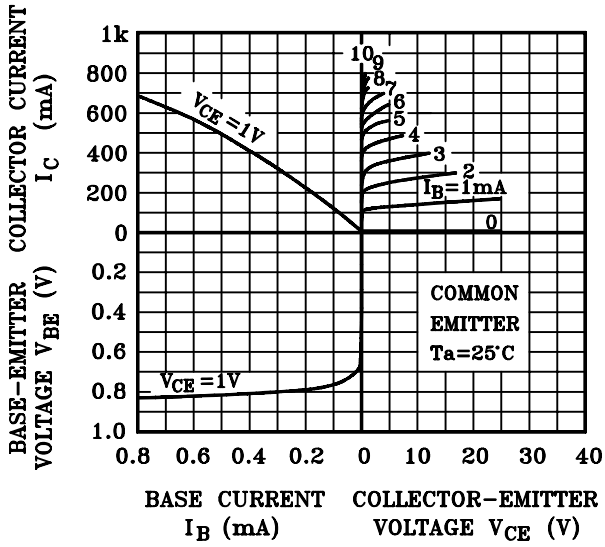


ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

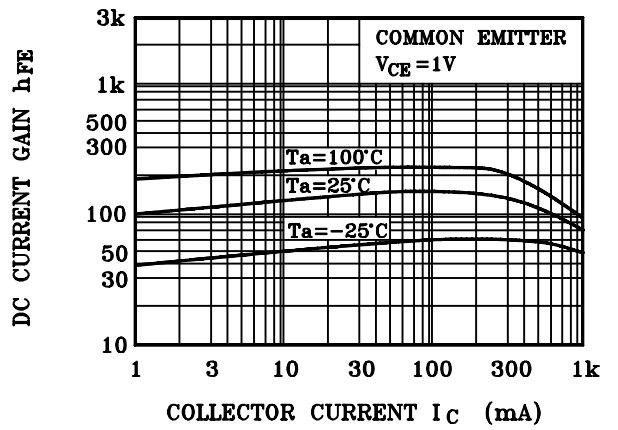
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=45\text{V}$, $I_E=0$	-	-	100	nA
DC Current Gain (Note)	h_{FE}	$V_{CE}=1\text{V}$, $I_C=100\text{mA}$	100	-	400	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=500\text{mA}$, $I_B=50\text{mA}$	-	-	0.7	V
Base-Emitter Voltage	$V_{BE(ON)}$	$V_{CE}=1\text{V}$, $I_C=300\text{mA}$	-	-	1.2	V
Transition Frequency	f_T	$V_{CE}=5\text{V}$, $I_C=10\text{mA}$, $f=100\text{MHz}$	-	100	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10\text{V}$, $f=1\text{MHz}$	-	12	-	pF

Note : h_{FE} Classification none:100~400 , 16:100~250 , 25:160~400

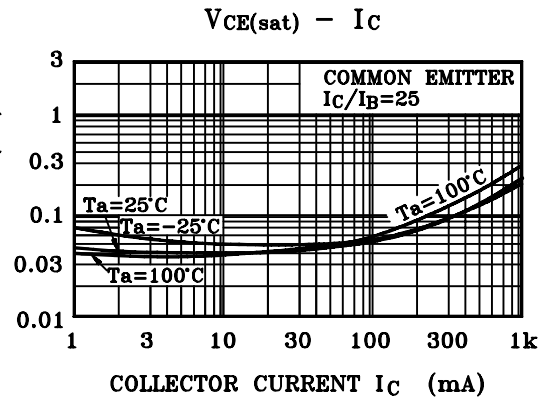
STATIC CHARACTERISTICS



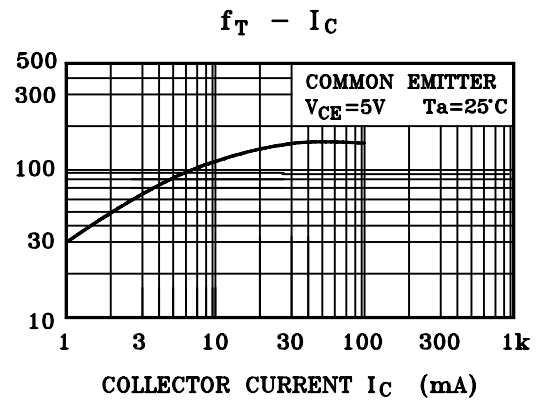
$h_{FE} - I_C$



COLLECTOR-EMITTER SATURATION VOLTAGE $V_{CE(sat)}$ (V)



TRANSITION FREQUENCY f_T (MHz)



COLLECTOR POWER DISSIPATION P_C (mW)

